

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



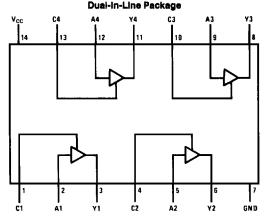
54LS126/DM74LS126A Quad TRI-STATE® Buffers

General Description

This device contains four independent gates each of which performs a non-inverting buffer function. The outputs have the TRI-STATE feature. When enabled, the outputs exhibit the low impedance characteristics of a standard LS output with additional drive capability to permit the driving of bus lines without external resistors. When disabled, both the

output transistors are turned off presenting a high-impedance state to the bus line. Thus the output will act neither as a significant load nor as a driver. To minimize the possibility that two outputs will attempt to take a common bus to opposite logic levels, the disable time is shorter than the enable time of the outputs.

Connection Diagram



Order Number 54LS126DMQB, 54LS126FMQB, DM74LS126AM or DM74LS126AN
See NS Package Number M14A, N14A or W14B

Function Table

Y = A

Inputs		Output		
Α	С	Y		
L	H	L		
н	Н	Н		
X	L	Hi-Z		

H = High Logic Level

L = Low Logic Level

X = Either Low or High Logic Level

Hi-Z = TRI-STATE (Outputs are disabled)

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V
Input Voltage 7V
Operating Free Air Temperature Range

Storage Temperature Range -65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	54LS126			DM74LS126A			Units
	T di dillotto	Min	Nom	Max	Min	Nom	Max	Office
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	٧
V _{IH}	High Level Input Voltage	2			2			٧
V _{IL}	Low Level Input Voltage			0.7			0.8	٧
łон	High Level Output Current			-1			-2.6	mA
loL	Low Level Output Current			12			24	mA
TA	Free Air Operating Temperature	-55		125	0		70	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$				-1.5	٧
VOH	High Level Output Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IH} = Min$		2.4			٧
V _{OL}	Low Level Output	V _{CC} = Min, I _{OL} = Max	54LS			0.4	
	Voltage	V _{IL} = Max, V _{IH} = Min	DM74		0.35	0.5	V
		$I_{OL} = 12 \text{ mA}, V_{CC} = \text{Min}$			0.25	0.4	
4	Input Current @ Max Input Voltage	$V_{CC} = Max, V_{\parallel} = 10V (54LS)$ $V_{\parallel} = 7V (DM74)$				0.1	mA
l _{IH}	High Level Input Current	V _{CC} = Max, V _I = 2.7V				20	μΑ
l _{IL}	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$				-0.4	mA
lozh	Off-State Output Current with High Level Output Voltage Applied	$V_{CC} = Max, V_O = 2.4V$ $V_{IH} = Min, V_{IL} = Max$				20	μΑ
lozL	Off-State Output Current with Low Level Output Voltage Applied	$V_{CC} = Max, V_O = 0.4V$ $V_{IH} = Min, V_{IL} = Max$				-20	μΑ
los	Short Circuit	V _{CC} = Max	54LS	-30		-130	mA
	Output Current	(Note 2)	DM74	-20		-100	IIIA
lcc	Supply Current	V _{CC} = Max (Note 3)	DM74		12	22	mA
ICCL	Supply Current	V _I = 0V	54LS			24	mA
1ссн	Supply Current	V _I = 4.5V	54LS			20	mA

Note 1: All typicals are at $V_{CC} = 5V$, $T_A = 25$ °C.

Note 2: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Note 3: I_{CC} is measured with both the output control and data inputs grounded.

Switching Characteristics at $V_{CC} = 5V$ and $T_A = 25^{\circ}C$ (See Section 1 for Test Waveforms and Output Load)

Symbol		54LS C _L = 50 pF		DM74LS C _L = 150 pF, R _L = 667Ω		Units
	Parameter					
		Min	Max	Min	Max	
t _{PLH}	Propagation Delay Time Low to High Level Output		15		21	ns
tpHL	Propagation Delay Time High to Low Level Output		18		22	ns
^t PZH	Output Enable Time to High Level Output		30		36	ns
tPZL	Output Enable Time to Low Level Output		20		42	ns
t _{PHZ}	Output Disable Time from High Level Output (Note 1)		30			ns
t _{PLZ}	Output Disable Time from Low Level Output (Note 1)		30			ns

Note 1: $C_L = 5pF$.